

SEMICONDUCTOR TM

# KSD1406

## Low Frequency Power Amplifier

- Low Collector-Emitter Saturation Voltage
- Complement to KSB1015



1.Base 2.Collector 3.Emitter

# **NPN Epitaxial Silicon Transistor**

Absolute Maximum Ratings  $T_{C}$ =25°C unless otherwise noted

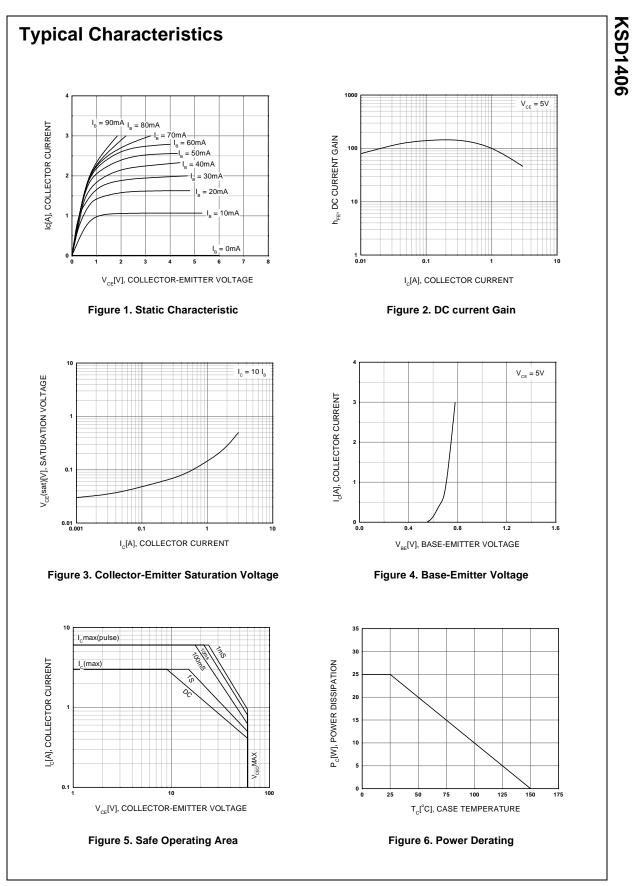
Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	60	V
V <sub>CEO</sub>	Collector-Emitter Voltage	60	V
V <sub>EBO</sub>	Emitter-Base Voltage	7	V
I <sub>C</sub>	Collector Current	3	А
I <sub>B</sub>	Base Current	0.5	А
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	25	W
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C

## Electrical Characteristics $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 50mA, I <sub>B</sub> = 0	60			V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = 60V, I_E = 0$			100	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 7V, I_{C} = 0$			100	μΑ
h <sub>FE1</sub> h <sub>FE2</sub>	DC Current Gain	$V_{CE} = 5V, I_C = 0.5A$ $V_{CE} = 5V, I_C = 3A$	60 20		300	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 3A, I <sub>B</sub> = 0.3A		0.4	1	V
V <sub>BE</sub> (on)	Base-Emitter ON Voltage	$V_{CE} = 5V, I_{C} = 0.5A$		0.7	1	V
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 5V, I_{C} = 0.5A$		3		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = 10V, f = 1MHz		70		pF
t <sub>ON</sub>	Turn ON Time	$V_{CC} = 30V, I_{C} = 1A$		0.8		μs
t <sub>STG</sub>	Storage Time	$I_{B1} = -I_{B2} = 0.2A$		1.5		μs
t <sub>F</sub>	Fall Time	$R_{L} = 30\Omega$		0.8		μs

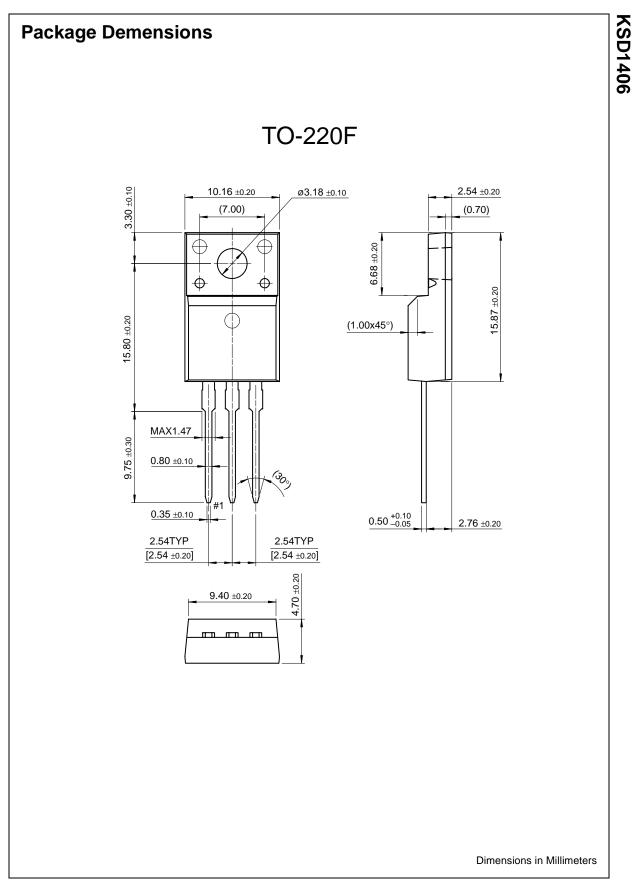
# h<sub>FE1</sub> Classification

Classification	0	Y	G
h <sub>FE1</sub>	60 ~ 120	100 ~ 200	150 ~ 300



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Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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# Applications

### Low Frequency Power Amplifier

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Product status/pricing/packaging

Product	Product status	Pricing*	Package type	Leads	Packing method
KSD1406GTU	Full Production	\$0.336	<u>TO-220F</u>	3	RAIL
KSD1406YTU	Full Production	\$0.349	<u>TO-220F</u>	3	RAIL
KSD1406OTU	Full Production	\$0.336	<u>TO-220F</u>	3	RAIL
KSD1406Y	Full Production	\$0.349	<u>TO-220F</u>	3	BULK

\* 1,000 piece Budgetary Pricing

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